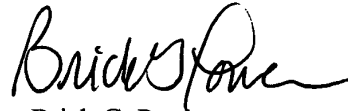


REMARKS

No new matter has been added. The Applicants again request entry of the amendments as set forth in the Appendices hereto prior to examination of the application on the merits.

Respectfully submitted,

A handwritten signature in black ink, appearing to read "Brick G. Power".

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Date: May 14, 2002

BGP/csw

N:\2269\3380.1\preliminary amendment.wpd

Serial No.: 10/067,410

**VERSION OF REPLACEMENT PARAGRAPH OF THE SPECIFICATION
WITH MARKINGS TO SHOW CHANGES MADE**

[0001] Cross-Reference to Related Application: This application is a continuation of application Serial No. 09/056,309, filed April 7, 1998, [pending]now U.S. Patent 6,372,643, issued April 16, 2002.

VERSION OF CLAIMS WITH MARKINGS TO SHOW CHANGES MADE

6. (Amended) The method of claim 1, further comprising cleaning [said]the
semiconductor device structure after said depositing said metal silicide.